

Current Transducer HAIS 50..400-P and HAIS 50..100-TP

For the electronic measurement of currents: DC, AC, pulsed, mixed, with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).









All Data are given with a $R_1 = 10 \text{ k}\Omega$

Electrical	data		
Primary nominal current rms I _{PN} (A)	Primary current, measuring range I _{PM} (A)	Туре	RoHS since date code
50	± 150	HAIS 50-P, HAIS 50-TP1)	45231, 46272
100	± 300	HAIS 100-P, HAIS 100-TP1)	45231, 46012
150	± 450	HAIS 150-P	46172
200	± 600	HAIS 200-P	45231
400	± 600	HAIS 400-P	planned

\mathbf{V}_{OUT}	Output voltage (Analog) @ I _p	V _{REF} ±(0.625	· I _P / I _{PN}) V
	$I_p = 0$	V _{REF} ± 0.025	
\mathbf{V}_{REF}	Reference voltage 2) - Output voltage	2.5 ± 0.025	V
	V _{REF} Output impedance	typ. 200	Ω
	V _{REF} Load impedance	≥ 200	$k\Omega$
$R_{\scriptscriptstyle L}$	Load resistance	≥ 2	kΩ
\mathbf{R}_{OUT}	Output internal resistance	< 10	Ω
C	Capacitive loading	< 1	μF
v c	Supply voltage (± 5 %)	5	V
I _C	Current consumption @ $V_c = 5 \text{ V}$	22	mΑ

A	D !		-1 - 4 -
Accuracy -	· Dynamic b	performance	gata
	_ , ,		

X	Accuracy $^{3)}$ @ I_{PN} , $T_{A} = 25^{\circ}C$	≤ ± 1	% of I _{PN}
$\mathbf{e}_{\scriptscriptstyle \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \! \!$	Linearity error 0 3 x I _{PN}	\leq ± 0.5	% of I _{PN}
TCV _{OE}	Temperature coefficient of $V_{OE} @ I_P = 0$	\leq ± 0.3	mV/K
TCV _{REF}	Temperature coefficient of V _{REF}	\leq ± 0.01	%/K
TCV_OUT/V_REF	Temperature coefficient of $\mathbf{V}_{OUT}/\mathbf{V}_{REF} @ \mathbf{I}_{P} = 0$	\leq ± 0.2	mV/K
TCV _{OUT}	Temperature coefficient of V _{out}	≤±0.05% d	of reading/K
$\mathbf{V}_{_{\mathrm{OM}}}$	Magnetic offset voltage @ $I_p = 0$,		
	after an overload of 3 x I _{PN DC}	$< \pm 0.4$	% of $\mathbf{I}_{\scriptscriptstyle{PN}}$
t _{ra}	Reaction time @ 10 % of I _{PN}	< 3	μs
t _r	Response time to 90 % of I_{PN} step	< 5	μs
di/dt	di/dt accurately followed	> 100	A/µs
\mathbf{V}_{no}	Output voltage noise (DC10 kHz)	< 15	mVpp
	(DC 1 MHz)	< 40	mVpp
BW	Frequency bandwidth (-3 dB) 4)	DC 50	kHz

Notes: 1) -TP version is equipped with a primary bus bar.

- 2) It is possible to overdrive V_{REF} with an external reference voltage between 2 - 2.8 V providing its ability to sink or source approximately 2.5 mA.
- 3) Excluding offset and hysteresis.
- ⁴⁾ Small signal only to avoid excessive heatings of the magnetic core.

$I_{PN} = 50 ... 400 A$



Features

- Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation test voltage 2500V
- Low power consumption
- Single power supply +5V
- Fixed offset & gain
- Bus bar version available for 50A and 100A ratings.
- Isolated plastic case recognized according to UL94-V0.

Advantages

- Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.
- V_{REF.} IN/OUT

Applications

- AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

Application domain

Industrial

Page 1/3



Current Transducer HAIS 50..400-P and HAIS 50..100-TP

Gener	al data			
T _A	Ambient operating temperature		- 40 + 8	85 °C
T _s	Ambient storage temperature		- 40 + 8	85 °C
m	Mass (in brackets : TP version)		20 (30)	g
	Standards		EN 5017	8: 1997
Isolati	on characteristics			
V _b	Rated isolation voltage rms with IEC 61010-1 standards and for Single insulation Over voltage category III Pollution degree 2	ollowing conditions	300 s	V rms
$\mathbf{V}_{_{\mathrm{b}}}$	- Heterogeneous field Rated isolation voltage rms with EN 50178 standards and follo - Reinforced insulation - Over voltage category III - Pollution degree 2	owing conditions	600	V rms
$oldsymbol{V}_{d} \ oldsymbol{V}_{e}$	 Heterogeneous field Rms voltage for AC isolation test, Partial discharge extinction voltag 		2.5	kV
		HAIS 50400-P	>1	kV
^		HAIS 50100-TP	> 1.4	kV
$\hat{\mathbf{V}}_{_{\mathbf{w}}}$	Impulse withstand voltage 1.2/50	μs	8	kV
dCp	Creepage distance		> 8	m m
dCl	Clearance distance		> 8	m m
СТІ	Comparative tracking index (Grou	o I)	> 600	
	If insulated cable is used for the p voltage category could be improve Cable insulation (primary) HAR 03 HAR 05 HAR 07	•	ng table :	

Safety



This transducer must be used in electric/electronic equipment with respect to applicable standards and safety requirements in accordance with the following manufacturer's operating instructions.



Caution! Risk of electrical shock

When operating the transducer, certain parts of the module can carry hazardous voltage (eg. primary busbar, power supply).

Ignoring this warning can lead to injury and/or cause serious damage.

This transducer is a built-in device, whose conducting parts must be inaccessible after installation.

A protective housing or additional shield could be used.

Main supply must be able to be disconnected.

Page 2/3

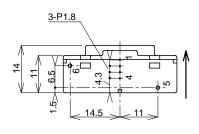


Dimensions HAIS 50..400-P and HAIS 50..100-TP (in mm. 1 mm = 0.0394 inch)

HAIS 50..400-P

Front view 33 15 2-D1.0 4-0.25x0.45

Bottom view



Terminal Pin Identification

- 1...+5V
- 2...0V
- 3...OUTPUT
- 4...Vref. (IN/OUT)
- 5...Core Earth (*)
- 6...NC.

Recommended PCB hole

Pin 1-4: 0.7 ±0.1mm Pin 5-6: 1.5 ±0.1mm

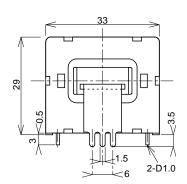
Primary bus bar: 2.3 ±0.1mm

General tolerance: ±0.2mm

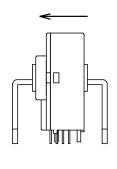
Unit: mm

HAIS 50..100-TP

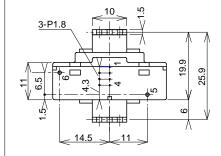
Front view



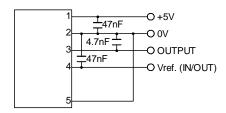
Right view



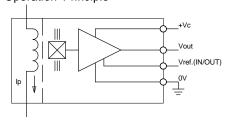
Bottom view



Required Connection Circuit



Operation Principle



(*) should be connected to 0V of Power Supply for better dv/dt immunity. Arrow indicates positive current direction.

Page 3/3